

LOW EMI CURRENT SENSE HIGH SIDE SWITCH

Features

- Load current feedback
- Programmable over current shutdown
- Active clamp
- ESD protection
- Input referenced to Vcc
- Over temperature shutdown
- Switching time optimized for low EMI
- Reverse battery protection
- Lead-Free, Halogen-Free, RoHS compliant

Description

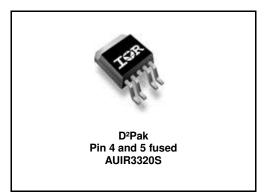
The AUIR3320(S) is a fully protected 4 terminals high side switch. The input signal is referenced to Vcc. When the input voltage Vcc - Vin is higher than the specified threshold, the output power Mosfet is turned on. When the Vcc - Vin is lower than the specified Vil threshold, the output Mosfet is turned off. A current proportional to the power Mosfet current is sourced to the lfb pin. Over current shutdown occurs when Vifb-Vin > 4.7V. The current shutdown threshold is adjusted by selecting the proper Rlfb. Either over current and over temperature latches off the switch. The device is reset by pulling the input pin high. Other integrated protections (ESD, reverse battery, active clamp) make the switch very rugged in automotive environment.

Rds(on) 4 m Ω max

Product Summary

Ras(on)	4 m <u>Ω</u> max.
Vcc op.	6 to 26V
Current Ratio	6000
Prog. Ishutdow	n 10 to 55A
Vclamp	40V

Packages

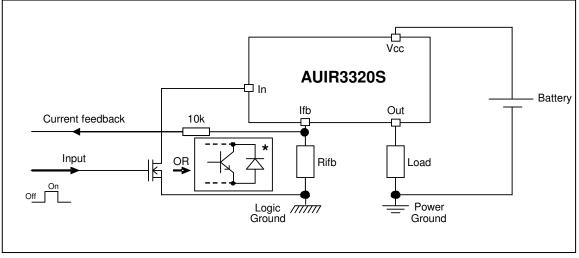


Ordering Information

Base Part Number		Standard Pack		
Dase Fart Number	Package Type	Form	Quantity	Complete Part Number
AUIR3320S	D2-Pak-5-Leads	Tape and reel left	800	AUIR3320STRL



Typical Connection



*The diode between the collector and the emitor is necessary for the reverse battery protection



Absolute Maximum Ratings Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are referenced to Vcc lead. (Ti=-40°..150°C, Vcc=6.26V Tambient=25°C unless otherwise specified).

Symbol	Parameter	Min.	Max.	Units
Vcc-Vin	Maximum Vcc voltage	-16	37	
Vcc-Vin cont.	Maximum continuous Vcc voltage	-16	26	v
Vcc-Vfb	Maximum Ifb voltage	-16	33	v
Vcc-Vout	Maximum output voltage	-0.3	37	
lds cont.	Maximum body diode continuous current Rth=60°C/W (1) Tambient=25°C	_	2.8	Α
lds pulsed	Maximum body diode pulsed current (1)		100	A
Pd	Maximum power dissipation Rth=60°C/W Tambient=25°C	_	2	W
Tj max.	Maximum operating junction temperature	-40	150	°C
ij max.	Maximum storage temperature	-55	150	U
Min Rfb	Minimum on the resistor on Ifb pin	0.3	_	kΩ
Ifb max.	Max. Ifb current	-50	50	mA

(1) Limited by junction temperature. Pulsed is also limited by wiring

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Units
Rth1	Thermal resistance junction to ambient D ² -Pak Std footprint	60	_	
Rth2	Thermal resistance junction to ambient D ² -Pak 1" sqrt. footprint	40	_	°C/W
Rth3	Thermal resistance junction to case D ² -Pak	0.7	_	

Recommended Operating Conditions

These values are given for a quick design. For operation outside these conditions, please consult the application notes.

Symbol	Parameter		Max.	Units
	Continuous output current			
lout	ut Tambient=85°C, Rth=5°C/W, Tj=150°C		45	Α
	Tambient=85°C, Rth=40°C/W, Tj=150°C	_	16	
Rifb	Recommended Ifb resistor (2)(3)		3.5	kΩ
Pulse min.	Minimum turn-on pulse width		_	ms
Fmax.	Maximum operating frequency		200	Hz

(2) If Rifb is too low, the device can be damaged.

(3) If Rifb is too high, the device may not switch on.



Protection Characteristics

Tj=-40°..150°C, Vcc=6..26V, Rifb=500 to 3.5kΩ. Typical value are given for Vcc=14V and Tj=25°C

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
Vifb-Vin@Isd	Over-current shutdown threshold	3.8	4.7	5.9	V	
Tsd	Over temperature threshold	—	165		°C	See fig. 5
OV	Over voltage protection (not latched)	26	29	33	V	
Isdf	Fixed over current shutdown	55	75	105	٨	Vifb <vifb-vin@isd< td=""></vifb-vin@isd<>
lsd_560	Programmable over current shutdown	34	50	71	A	Rifb=560Ω
Treset	Time to reset protection	_	50	500		See fig. 5
Min. pulse	Min. pulse width (no WAIT state)	_	900	2000	μs	Tj=25°C
WAIT	WAIT function timer	0.4	1	2	ms	See fig. 4 and 5
Rds(on) rev.	Reverse battery On state resistance, Tj=25°C	_	4	6	mΩ	Vcc-Vin=-14V,
	Tj=125°C		6	9		lout=30A

Static Electrical Characteristics

Tj=-40°..150°C, Vcc=6..26V (unless otherwise specified). Typical value are given for Vcc=14V and Tj=25°C

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
Vcc op.	Operating Voltage range	6	_	26	V	
Icc off	Supply leakage current	_	1.5	5	μA	Vin=Vcc, Vcc-Vout=14V, Vcc-Vifb=14V, Tj=25°C
lin, on	On state IN positive current	1.5	3	6	mA	Vcc-Vin=14V, Tj=25°C
Vih	High level Input threshold voltage (4)	_	5.4	6.3		
Vil	Low level Input threshold voltage (4)	4	4.9	5.8	V	
Vhyst	Input hysteresis Vih-Vil	0.2	0.4	1.5		
lout	Drain to source leakage current	-	1.2	5	μA	Vin=Vcc, Vcc-Vifb=0V, Vcc-Vout=14V, Tj=25°C
	On state resistance (5) Tj=25°C	_	3.3	4		lout=30A, Vcc-Vin=14V
Rds(on)	On state resistance (5) Tj=25°C	_	3.5	5.5	mΩ	lout=17A, Vcc-Vin=6V
	On state resistance (5)(6) Tj=150°C	_	5.5	6.5		lout=30A, Vcc-Vin=14V
V clamp1	Vcc to Vout clamp voltage 1	36	39	43	V	lout=50mA
V clamp2	Vcc to Vout clamp voltage 2	_	40		v	lout=30A, Tj=25°C

(4) Input thresholds are measured directly between the input pin and the tab. Any parasitic resistance in common between the load current path and the input signal path can significantly affect the thresholds.

(5) Rdson is measured between the tab and the Out pin, 5mm away from the package.

(6) Guaranteed by design

Switching Electrical Characteristics

Vcc=14V, Resistive load=0.5Ω, Tj=25°C

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
Tdon	Turn on delay time to 10% Vcc	70	170	300		
tr1	Rise time to Vcc-Vout=5V	30	100	210	μs	
tr2	Rise time to Vcc-Vout=0.1Vcc	30	125	250		
Eon	Turn on energy	_	15		mJ	See figure 2
Tdoff	Turn off delay time	30	70	140		
Tf	Fall time to Vout=10% of Vcc	20	100	250	μs	
Eoff	Turn off energy	_	9	-	mJ	



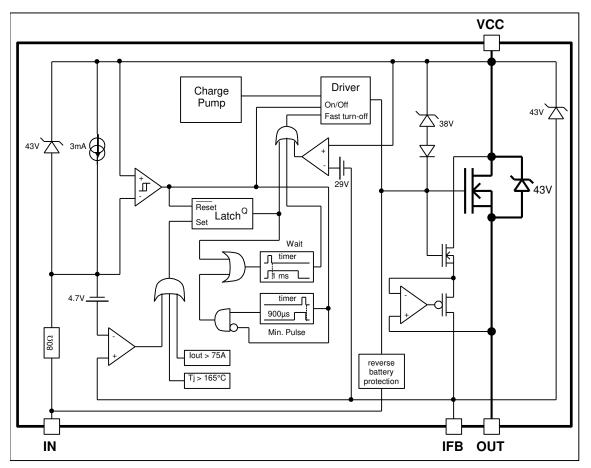
Current Sense Characteristics

Tj=-40°..150°C, Vcc=6..26V (unless otherwise specified). Typical value are given for Vcc=14V and Tj=25°C

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
Ratio	I Load/lifb current ratio	4900	6000	6600	_	Rifb=500Ω, lout=30A
Ratio_TC	I Load/lifb variation over temperature (6)	-4	-	+4	%	Tj=-40°C to 150°C
Offset	Load current diagnostic offset	-0.4	0	+0.4	Α	lout=2A
Trst	Ifb response time (low signal)		1		μs	90% of the lout step

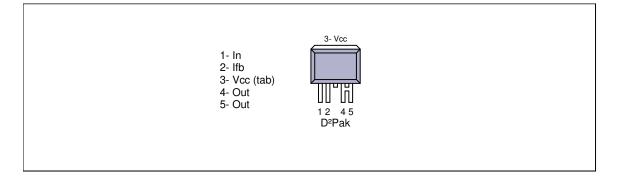
Functional Block Diagram

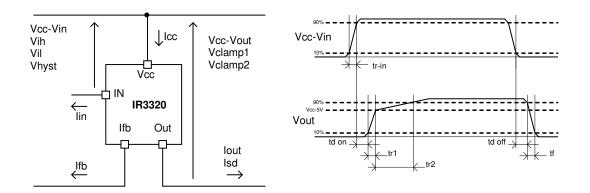
All values are typical





Lead Assignments





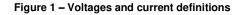
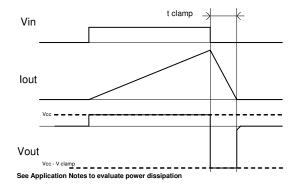


Figure 2 – Switching time definitions





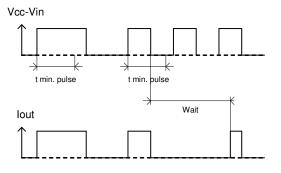
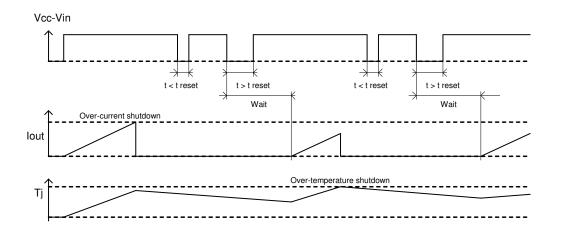


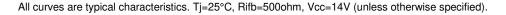
Figure 3 – Active clamp waveforms

Figure 4 – Min. pulse and Wait function









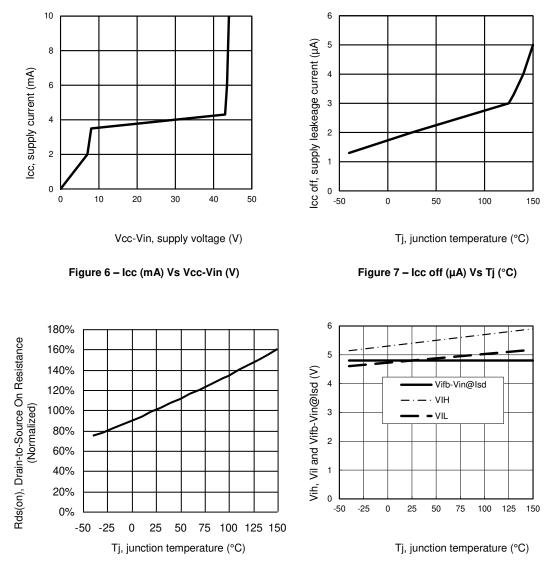
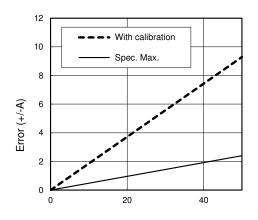


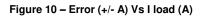
Figure 8 - Normalized Rds(on) (%) Vs Tj (°C)

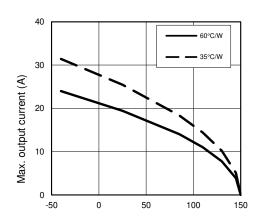
Figure 9 – Vih, Vil and Vifb-Vin@lsd (V) Vs Tj (°C)





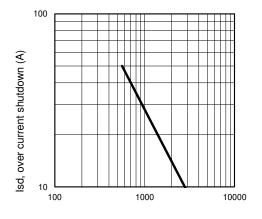
I load, load current (A)





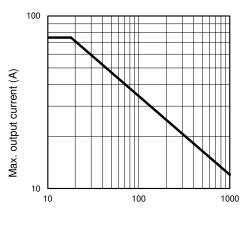
Tamb., ambient temperature (°C)

Figure 12 – Max. lout (A) Vs Tamb. (°C)

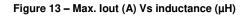


Rifb, feedback resistor (Ω)

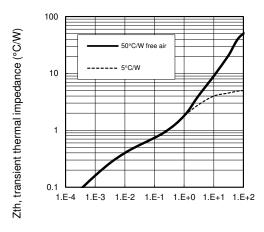
Figure 11 – Ids (A) Vs Rifb (Ω)



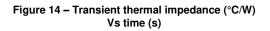
Inductance (µH)







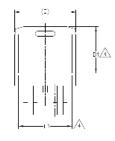


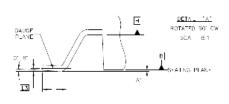


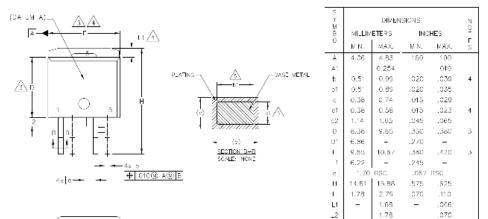




Case Outline - D2PAK - 5 Leads



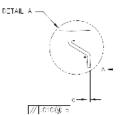












NOTES:

1. DIMENSIONING AND TOLERANGING AS PER ASME M14.5M 1994

_3

0.25 BSC

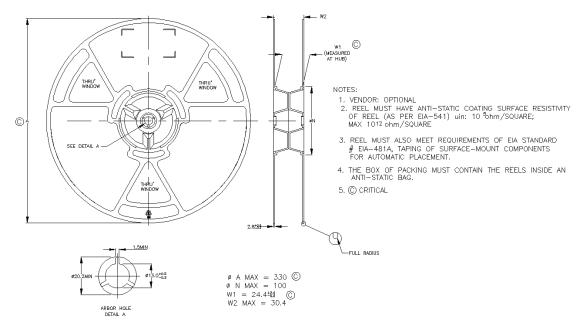
.010 BSC

- 2. DIMENSIONS ARE SHOWN IN MITHERS INCLUSE.
- A primer d & do not not definite Lash, no d Ash SFALL NOT EXCEED 0.127 [Loos"] PER SIDE. THESE DIVENSIONS ARE MEASURED AT THE OUTWOST EXTERMES OF THE F ASTIC BODY A DATUM IL.
- A --RMA PAD CONTOUR OP CHAL WIFEN DIM-NSION -, 1, D1 & -1.
- S DIMENSION 51 AND 61 APPLY TO BASE METAL ONLY.
- 6. DATUM A & B TO BE DETERMINED AT DATUM PLANE L.
- 7. CONTRO ENG DIMENSION: INC.L.
- 8. OU INF CONFORMS TO JED-C OU INF TO-2638A.



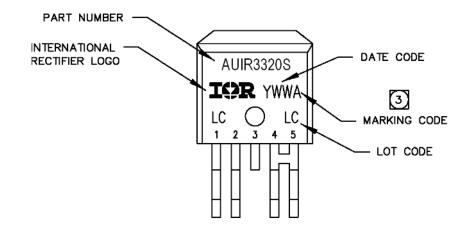
AUIR3320S

Tape & Reel - D2PAK - 5 leads





Part Marking Information



Qualification Information⁺

Qualificati	on Level	Automotive (per AEC-Q100) Comments: This family of ICs has passed an Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.			
Moisture Sensitivity Level		D2PAK-5L	MSL1, 260°C (per IPC/JEDEC J-STD-020)		
	Machine Model	Class M3 (400V) (per AEC-Q100-003)			
ESD	Human Body Model	Class H2 (4 (per AEC-Q1	,000 V)		
Charged Device Model		Class C4 (1000 V) (per AEC-Q100-011)			
IC Latch-Up Test Class II, Level A (per AEC-Q100-004)					
RoHS Con	npliant	Yes			





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Revision History

Revision	Date	Notes/Changes
A7	June, 4 th 2012	Initial release
A8	August, 13rd 2012	-Update switching limits -Update Iratio max limit
A9	August, 30 th 2012	Update Tj max.
Rev1.0	July, 11 th 2017	 Page 'Case Outline - D2PAK - 5 Leads' updated Page 'Ordering information' updated Page 14 'Notice' updated